

SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company



Monolithic Linear IC – Halogen-free Digital Ambient Light Sensor

Overview

LV0104CS is a Photo IC for micro-sized Ambient Light sensor which has the characteristics of spectral response similar to that of human eyes. It is suitable for the applications like mobile phone (for Digital-TV, One-segment), LCD-TV, laptop computer, PDA, DSC and Camcorder.

Functions

- Smallest OD-CSP package in the world (1.08mm × 1.08mm thickness: 0.6mm)
- Great spectrum sensitivity characteristic
- 16-Bit Digital Output for I²C-BUS
- Low Current consumption, Integrated Sleep function

Specifications Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Power Supply Voltage	V _{DD}		4.0	V
Logic I/O levels	V _{IO}		-0.3 to V _{DD} +0.3	V
Operating temperature range	Topr		-30 to 85	°C
Storage temperature range	Tstg		-40 to 100	°C

Recommended Operating Conditions at Ta = 25°C

Parameter	Symbol	Condition	Min.	Тур	Max.	Unit
Recommended Supply Voltage	V _{DD} op		2.3	2.5	3.6	V
Input low level voltage	VIL	SCL, SDA			0.55	V
Input high level voltage	VIН	SCL, SDA ,VDD=2.8V	1.26			V
Output low level voltage	V _O L	SDA, IOL=3mA			0.4	V
Input leak current	ILEAK	SCL,SDA	-5		5	μA

* I²C interface(SCL,SDA) is for Vio=1.8V operation.

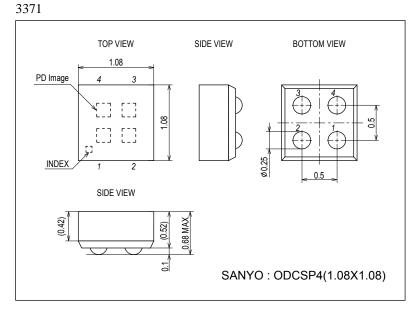
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LV0104CS

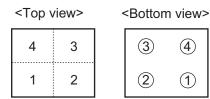
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit
Supply Current	I _{DD}	Ev=0 lux		70	100	μA
Sleep Current	I _{SLP}	Sleep mode, Ev=0 lux			1	μA
Internal Oscillator Frequency	fosc			655		kHz
Dark ADC count value	D0	Ev=0 lux, High gain mode			5	counts
Full scale ADC count value	D max				65535	counts
	Data HH	Gain×8mode, Ev=1000lx		8000		counts
	Data HM	Gain×2 mode, Ev=1000lx		2000		counts
ADC count value	Data N	Gain×1 mode, Ev=1000lx	750	1000	1250	counts
	Data L	Gain×0.25 mode, Ev=1000lx		250		counts
	ReHH1	Tint=200ms, Gain×8 mode		0.125		lx
	ReHH2	Tint=100ms, Gain×8 mode		0.25		lx
	ReHH3	Tint=12.5ms, Gain×8 mode		2		lx
	ReHM1	Tint=200ms, Gain×2 mode		0.5		lx
	ReHM2	Tint=100ms, Gain×2 mode		1		lx
Resolution	ReHM3	Tint=12.5ms, Gain×2 mode		8		lx
Resolution	ReN1	Tint=200ms, Gain×1 mode		1		lx
	ReN2	Tint=100ms, Gain×1 mode		2		lx
	ReN3	Tint=12.5ms, Gain×1 mode		16		lx
	ReL1	Tint=200ms, Gain×0.25 mode		4		lx
	ReL2	Tint=100ms, Gain×0.25 mode		8		lx
	ReL3	Tint=12.5ms, Gain×0.25 mode		64		lx

Package Dimensions

unit : mm (typ)



Pad layout



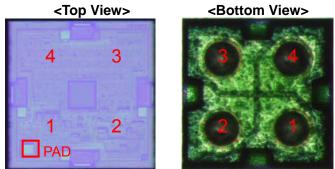
Name Function No. 1 Supply voltage pin V_{CC} 2 GND GND pin SCL I²C serial clock 3 I²C serial data 4 SDA

Ball Pitch: 0.5mm, Ball Size: 0.25mm

4

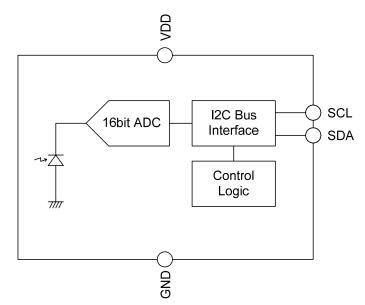
1

Pad layout (Photos)

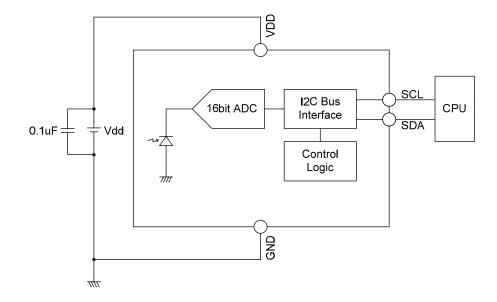


* The position with PAD becomes pin 1.

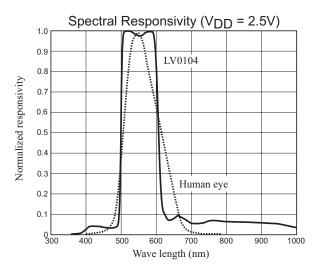
Block Diagram



Application circuits



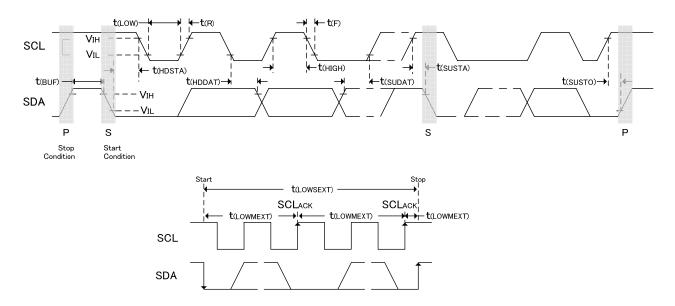
Spectrum Sensitivity Characteristic



I²C Interface

The control command is received from the operation of the device by the I^2C bus (Two-wire serial interface). The obtained data is output to the operation by the I^2C bus.

I²C Bus Timing Diagram



Serial Interface Timing

Demonden	0 subst	Standar	d Mode	Fast	Mode	11.2
Parameter	Symbol	Min	Min	Min	Max	Unit
Clock frequency	f(SCL)	10	100	10	400	kHz
Bus free time between start and stop condition	t(BUF)	4.7		1.3		μs
Hold time after (repeated) start condition. After this period, the first	t(HDSTA)	4.0		0.6		μs
Repeated start condition setup time	t(SUSTA)	4.7		0.6		μs
Stop condition setup time	t(SUSTO)	4.0		0.6		μs
Data hold time	t(HDDAT)	300		90		ns
Data setup time	t(SUDAT)	250		100		ns
I ² C clock (SCL) low period	t(LOW)	4.7		1.3		μs
I ² C clock (SCL) high period	t(HIGH)	4.0		0.6		μs
Clock / data fall time	t(F)		300		300	ns
Clock / data rise time	t(R)		1000		300	ns

*Specified by design and characterization ; not production tested.

Data Format (Write)

	∢		Slav	e Add	Iress					◄			Data	Byte						
S	A6	A5	A4	A3	A2	A1	A0	R/W	А	D7	D6	D5	D4	D3	D2	D1	D0	А	Р	

Data Format (Read)

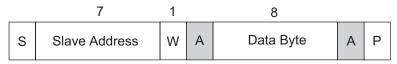
	-			Slave	e Add	lress					◀		— Da	ata Hi	gh By	vte —				◀		— Da	ita Lo	w Byt	ie —				
s	A	.6	A5	A4	A3	A2	A1	A0	R/W	А	D15	D14	D13	D12	D11	D10	D9	D8	А	D7	D6	D5	D4	D3	D2	D1	D0	А	Р

Slave Address

A6	A5	A4	A3	A2	A1	A0	R/W					
0	0	1	0	0	1	1	х					
DAV. Dead. 1 Writer O												

R/W: Read: 1, Write: 0

(1) Write Protocol (R/W=0)



(2) Read Protocol (R/W=1)



- S: Start Condition
- P: Stop Condition
- A: Acknowledge
- W: Write
- R: Read

Register Set

(1) Measurement

	D7	D6	D5	D4	D3	D2	D1	D0
Name	MODE1	MODE0	-	GAIN1	GAIN0	INTEG1	INTEG0	MANUAL
	11:A	ctive		00: x	0.25	00: 12	2.5ms	0: Start
				01:	x1	01: 1	00ms	1: Stop
				10:	x2	10: 2	00ms	
				11: :	x8	11: M	anual	
Default	0	0	1	0	1	1	0	0

(2) Sleep mode

	D7	D6	D5	D4	D3	D2	D1	D0
Name	MODE1	MODE0	-	-	-	-	-	-
	00:Sleep		х	х	х	х	х	х
Default	0	0	х	х	х	х	х	х

(3) Setting Sensitivity

	D7	D6	D5	D4	D3	D2	D1	D0
Name	MODE1 MODE0		ADJ5	ADJ4	ADJ3	ADJ2	ADJ1	ADJ0
	10:Se	etting	0: Minus 1: Plus	ADJ4	ADJ3	ADJ2	ADJ1	ADJ0
Default	00		0	0	0	0	0	0

		Bits D5	to D0			Description
ADJD	ADJ4	ADJ3	ADJ2	ADJ1	ADJ0	Description
0	0	0	0	0	1	66.7%
		•				
		•		•		
0	0	1	0	1	0	95.2%
	•	•	•	•		
		•		•	•	
1	0	0	1	1	0	108.3%
	•	•	•	•		
		•		•	•	
1	0	0	0	0	1	150%

<Width of sensitivity adjustment>

66.7% to150% (ADJ5 to ADJ0=000001=66.7%, ADJ5 to ADJ0 = 100001 = 150%)

<Sensitivity Calculation>

• Decreasing Sensitivity (ADJ5=0) Sn=16*ADJ4 + 8*ADJ3 + 4*ADJ2 + 2*ADJ1 + ADJ0 S=2*Sn / (2*Sn+1) (Example) ADJ5 to ADJ0 = 001010, Sn=8+2=10, S=20/21=0.952. The sensitivity is 95.2%

• Increasing Sensitivity (ADJ5=1) Sn =16*ADJ4 + 8*ADJ3 + 4*ADJ2 + 2*ADJ1 + ADJ0 S=(2*Sn+1) / 2*Sn (Example) ADJ5 to ADJ0=100110, Sn=4+2=6, S=13/12=1.083. The sensitivity is 108.3%.

(4) Read data

Measurement result is registered to ADC channel data registers (DH,DL) in below format.

	D15	D14	D13	D12	D11	D10	D9	D8
DH (Data Higher byte)	DH7(2 ¹⁵)	DH6(2 ¹⁴)	DH5(2 ¹³)	DH4(2 ¹²)	DH3(2 ¹¹)	DH2(2 ¹⁰)	DH1(2 ⁹)	DH0(2 ⁸)
	D7	D6	D5	D4	D3	D2	D1	D0

	D7	D6	D5	D4	D3	D2	D1	D0
DL (Data Lower byte)	DL7(2 ⁷)	DL6(2 ⁶)	DL5(2⁵)	DL4(2 ⁴)	DL3(2 ³)	DL2(2 ²)	DL1(2 ¹)	DL0(2 ⁰)

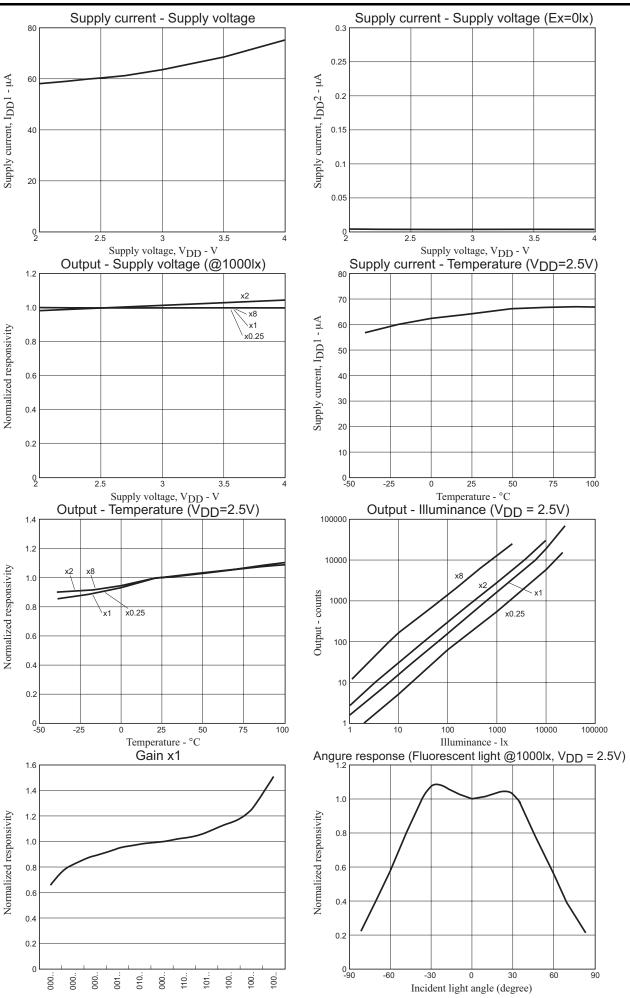
• Lux calculation

(Example)

DH = "0010_0100" (DH5, DH2 = 1) DL = "1000_0001" (DL7, DL0 = 1)

 $2^{13}(8192) + 2^{10}(1024) + 2^{7}(128) + 2^{0}(1) = 9345[lx]$

LV0104CS



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